

L293x Quadruple Half-H Drivers

1 Features

- Wide Supply-Voltage Range: 4.5 V to 36 V
- Separate Input-Logic Supply
- Internal ESD Protection
- High-Noise-Immunity Inputs
- Output Current 1 A Per Channel (600 mA for L293D)
- Peak Output Current 2 A Per Channel (1.2 A for L293D)
- Output Clamp Diodes for Inductive Transient Suppression (L293D)

2 Applications

- Stepper Motor Drivers
- DC Motor Drivers
- Latching Relay Drivers

3 Description

The L293 and L293D devices are quadruple high-current half-H drivers. The L293 is designed to provide bidirectional drive currents of up to 1 A at voltages from 4.5 V to 36 V. The L293D is designed to provide bidirectional drive currents of up to 600-mA at voltages from 4.5 V to 36 V. Both devices are designed to drive inductive loads such as relays, solenoids, DC and bipolar stepping motors, as well as other high-current/high-voltage loads in positive-supply applications.

Each output is a complete totem-pole drive circuit, with a Darlington transistor sink and a pseudo-Darlington source. Drivers are enabled in pairs, with drivers 1 and 2 enabled by 1,2EN and drivers 3 and 4 enabled by 3,4EN.

The L293 and L293D are characterized for operation from 0°C to 70°C.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
L293NE	PDIP (16)	19.80 mm × 6.35 mm
L293DNE	PDIP (16)	19.80 mm × 6.35 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram

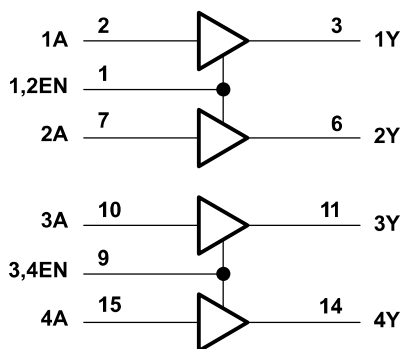


Table of Contents

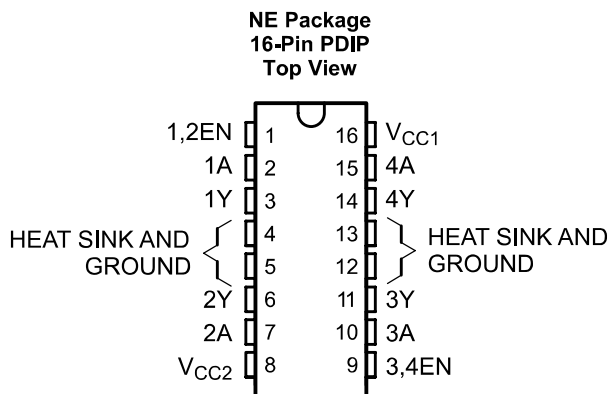
1 Features	1	8.3 Feature Description	7
2 Applications	1	8.4 Device Functional Modes	8
3 Description	1	9 Application and Implementation	9
4 Revision History	2	9.1 Application Information	9
5 Pin Configuration and Functions	3	9.2 Typical Application	9
6 Specifications	4	9.3 System Examples	10
6.1 Absolute Maximum Ratings	4	10 Power Supply Recommendations	13
6.2 ESD Ratings	4	11 Layout	14
6.3 Recommended Operating Conditions	4	11.1 Layout Guidelines	14
6.4 Thermal Information	4	11.2 Layout Example	14
6.5 Electrical Characteristics	5	12 Device and Documentation Support	15
6.6 Switching Characteristics	5	12.1 Related Links	15
6.7 Typical Characteristics	5	12.2 Community Resources	15
7 Parameter Measurement Information	6	12.3 Trademarks	15
8 Detailed Description	7	12.4 Electrostatic Discharge Caution	15
8.1 Overview	7	12.5 Glossary	15
8.2 Functional Block Diagram	7	13 Mechanical, Packaging, and Orderable Information	15

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (November 2004) to Revision D	Page
• Removed <i>Ordering Information</i> table	1
• Added <i>ESD Ratings</i> and <i>Thermal Information</i> tables, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section.	1

5 Pin Configuration and Functions



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
1,2EN	1	I	Enable driver channels 1 and 2 (active high input)
<1:4>A	2, 7, 10, 15	I	Driver inputs, noninverting
<1:4>Y	3, 6, 11, 14	O	Driver outputs
3,4EN	9	I	Enable driver channels 3 and 4 (active high input)
GROUND	4, 5, 12, 13	—	Device ground and heat sink pin. Connect to printed-circuit-board ground plane with multiple solid vias
V _{CC1}	16	—	5-V supply for internal logic translation
V _{CC2}	8	—	Power VCC for drivers 4.5 V to 36 V

6 Specifications

6.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage, V_{CC1} ⁽²⁾		36	V
Output supply voltage, V_{CC2}		36	V
Input voltage, V_I		7	V
Output voltage, V_O	–3	$V_{CC2} + 3$	V
Peak output current, I_O (nonrepetitive, $t \leq 5$ ms): L293	–2	2	A
Peak output current, I_O (nonrepetitive, $t \leq 100$ μ s): L293D	–1.2	1.2	A
Continuous output current, I_O : L293	–1	1	A
Continuous output current, I_O : L293D	–600	600	mA
Maximum junction temperature, T_J		150	°C
Storage temperature, T_{stg}	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the network ground terminal.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	
		±2000	
		±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply voltage	V_{CC1}	4.5		7	V
	V_{CC2}	V_{CC1}		36	
V_{IH}	High-level input voltage	$V_{CC1} \leq 7$ V		V_{CC1}	V
		$V_{CC1} \geq 7$ V	2.3	7	V
V_{IL}	Low-level output voltage	–0.3 ⁽¹⁾		1.5	V
T_A	Operating free-air temperature	0		70	°C

- (1) The algebraic convention, in which the least positive (most negative) designated minimum, is used in this data sheet for logic voltage levels.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		L293, L293D	UNIT
		NE (PDIP)	
		16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽²⁾	36.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	22.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	16.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	7.1	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	16.3	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).
- (2) The package thermal impedance is calculated in accordance with JESD 51-7.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V _{OH}	High-level output voltage	L293: I _{OH} = -1 A		V _{CC2} - 1.8	V _{CC2} - 1.4		V
		L293D: I _{OH} = -0.6 A					
V _{OL}	Low-level output voltage	L293: I _{OL} = 1 A			1.2	1.8	V
		L293D: I _{OL} = 0.6 A					
V _{OKH}	High-level output clamp voltage	L293D: I _{OK} = -0.6 A		V _{CC2} + 1.3			V
V _{OKL}	Low-level output clamp voltage	L293D: I _{OK} = 0.6 A		1.3			V
I _{IH}	High-level input current	A	V _I = 7 V	0.2		100	μA
		EN		0.2		10	
I _{IL}	Low-level input current	A	V _I = 0	-3		-10	μA
		EN		-2		-100	
I _{CC1}	Logic supply current	I _O = 0	All outputs at high level	13		22	mA
			All outputs at low level	35		60	
			All outputs at high impedance	8		24	
I _{CC2}	Output supply current	I _O = 0	All outputs at high level	14		24	mA
			All outputs at low level	2		6	
			All outputs at high impedance	2		4	

6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted) V_{CC1} = 5 V, V_{CC2} = 24 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay time, low-to-high-level output from A input	L293NE, L293DNE		800			ns
		L293DWP, L293N L293DN		750			
t _{PHL}	Propagation delay time, high-to-low-level output from A input	L293NE, L293DNE		400			ns
		L293DWP, L293N L293DN		200			
t _{TLH}	Transition time, low-to-high-level output	L293NE, L293DNE		300			ns
		L293DWP, L293N L293DN		100			
t _{THL}	Transition time, high-to-low-level output	L293NE, L293DNE		300			ns
		L293DWP, L293N L293DN		350			

6.7 Typical Characteristics

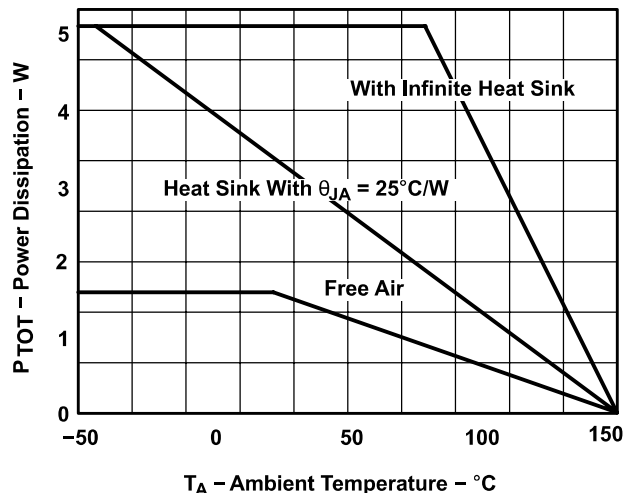
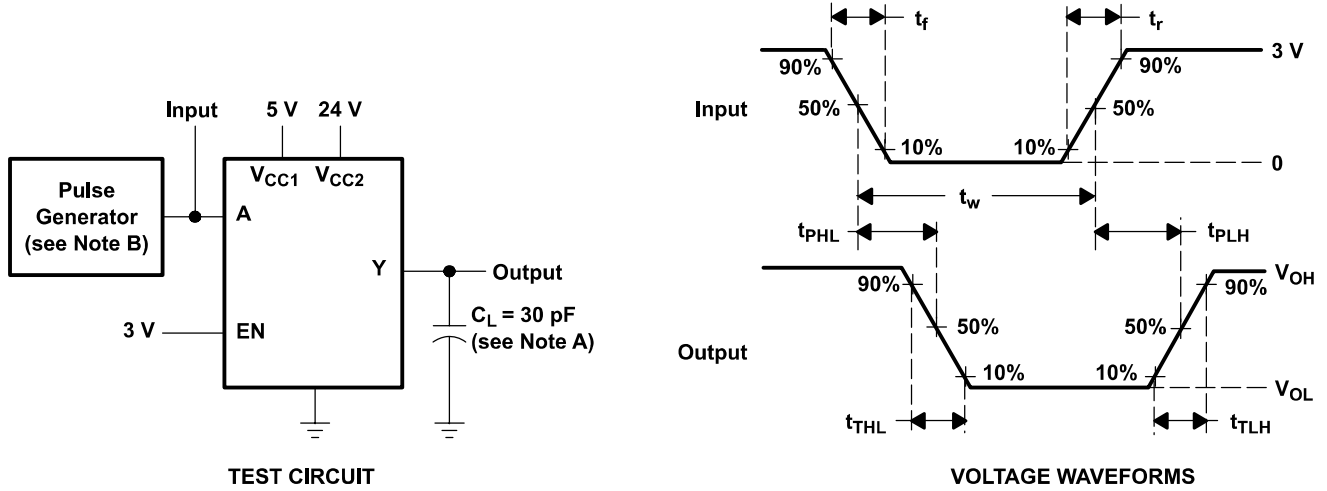


Figure 1. Maximum Power Dissipation vs Ambient Temperature

7 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $t_r \leq 10$ ns, $t_f \leq 10$ ns, $t_w = 10$ μ s, PRR = 5 kHz, $Z_O = 50$ Ω .

Figure 2. Test Circuit and Voltage Waveforms

8 Detailed Description

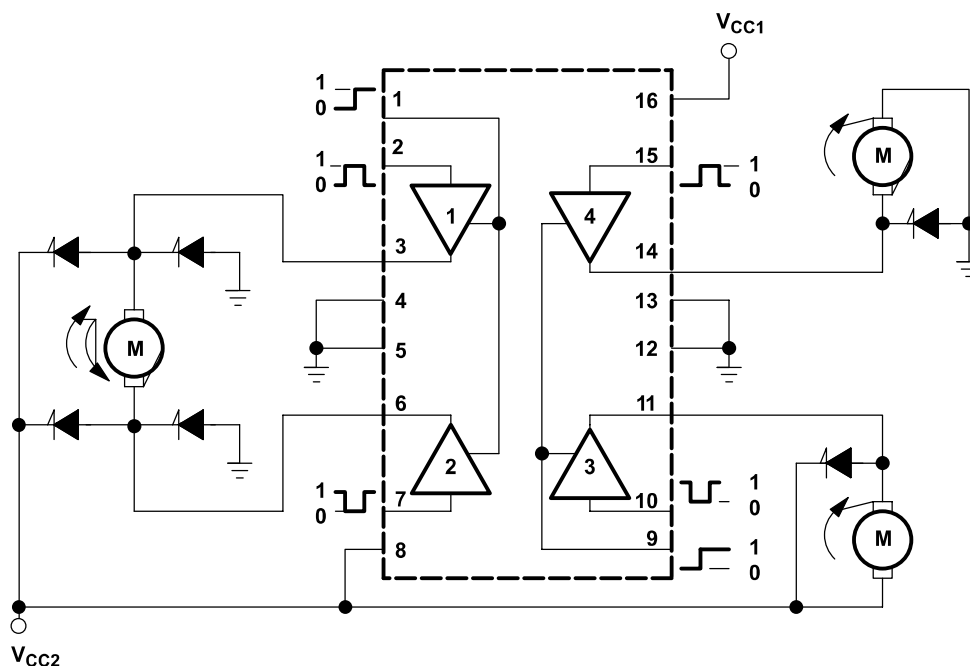
8.1 Overview

The L293 and L293D are quadruple high-current half-H drivers. These devices are designed to drive a wide array of inductive loads such as relays, solenoids, DC and bipolar stepping motors, as well as other high-current and high-voltage loads. All inputs are TTL compatible and tolerant up to 7 V.

Each output is a complete totem-pole drive circuit, with a Darlington transistor sink and a pseudo-Darlington source. Drivers are enabled in pairs, with drivers 1 and 2 enabled by 1,2EN and drivers 3 and 4 enabled by 3,4EN. When an enable input is high, the associated drivers are enabled, and their outputs are active and in phase with their inputs. When the enable input is low, those drivers are disabled, and their outputs are off and in the high-impedance state. With the proper data inputs, each pair of drivers forms a full-H (or bridge) reversible drive suitable for solenoid or motor applications.

On the L293, external high-speed output clamp diodes should be used for inductive transient suppression. On the L293D, these diodes are integrated to reduce system complexity and overall system size. A V_{CC1} terminal, separate from V_{CC2} , is provided for the logic inputs to minimize device power dissipation. The L293 and L293D are characterized for operation from 0°C to 70°C.

8.2 Functional Block Diagram



Output diodes are internal in L293D.

8.3 Feature Description

The L293x has TTL-compatible inputs and high voltage outputs for inductive load driving. Current outputs can get up to 2 A using the L293.

8.4 Device Functional Modes

Table 1 lists the functional modes of the L293x.

Table 1. Function Table (Each Driver)⁽¹⁾

INPUTS ⁽²⁾		OUTPUT (Y)
A	EN	
H	H	H
L	H	L
X	L	Z

- (1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)
- (2) In the thermal shutdown mode, the output is in the high-impedance state, regardless of the input levels.

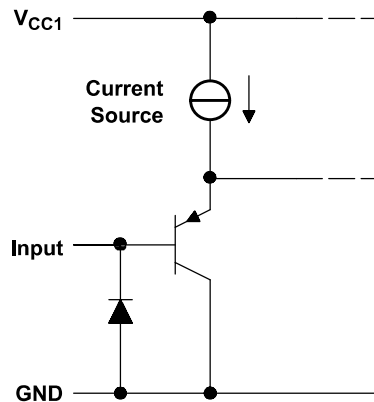


Figure 3. Schematic of Inputs for the L293x

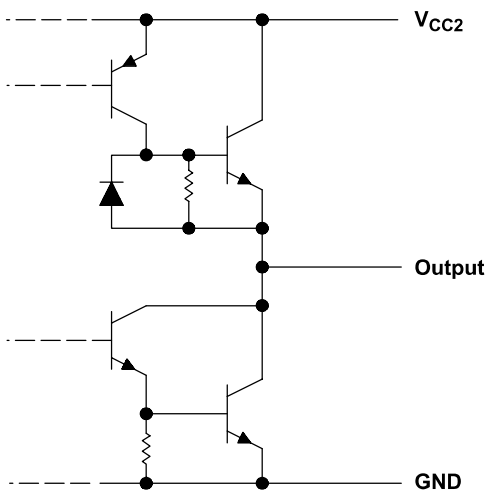


Figure 4. Schematic of Outputs for the L293

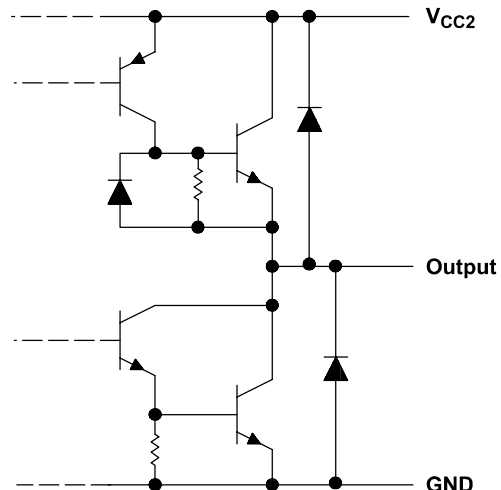


Figure 5. Schematic of Outputs for the L293D

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

A typical application for the L293 device is driving a two-phase motor. Below is an example schematic displaying how to properly connect a two-phase motor to the L293 device.

Provide a 5-V supply to V_{CC1} and valid logic input levels to data and enable inputs. V_{CC2} must be connected to a power supply capable of supplying the needed current and voltage demand for the loads connected to the outputs.

9.2 Typical Application

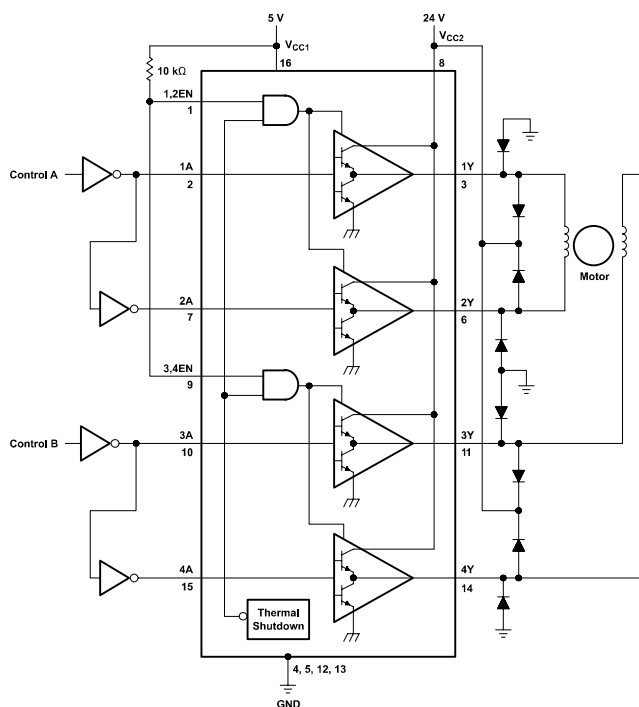


Figure 6. Two-Phase Motor Driver (L293)

9.2.1 Design Requirements

The design techniques in the application above as well as the applications below should fall within the following design requirements.

1. V_{CC1} should fall within the limits described in the [Recommended Operating Conditions](#).
2. V_{CC2} should fall within the limits described in the [Recommended Operating Conditions](#).
3. The current per channel should not exceed 1 A for the L293 (600mA for the L293D).

9.2.2 Detailed Design Procedure

When designing with the L293 or L293D, careful consideration should be made to ensure the device does not exceed the operating temperature of the device. Proper heatsinking will allow for operation over a larger range of current per channel. Refer to the [Power Supply Recommendations](#) as well as the [Layout Example](#).

Typical Application (continued)

9.2.3 Application Curve

Refer to [Power Supply Recommendations](#) for additional information with regards to appropriate power dissipation. [Figure 7](#) describes thermal dissipation based on [Figure 14](#).

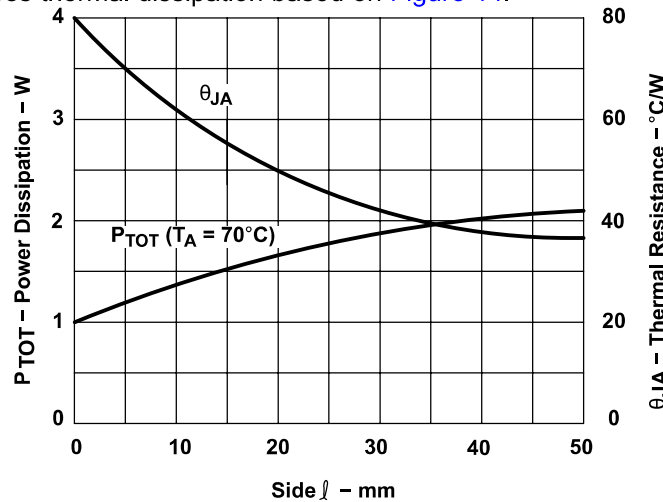


Figure 7. Maximum Power and Junction vs Thermal Resistance

9.3 System Examples

9.3.1 L293D as a Two-Phase Motor Driver

[Figure 8](#) below depicts a typical setup for using the L293D as a two-phase motor driver. Refer to the [Recommended Operating Conditions](#) when considering the appropriate input high and input low voltage levels to enable each channel of the device.

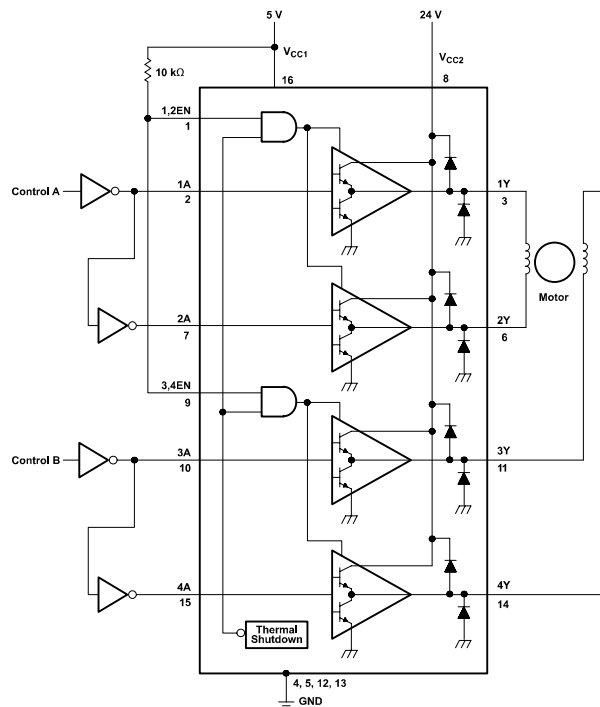
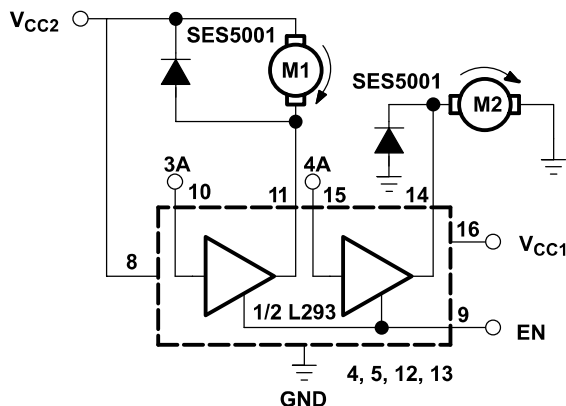


Figure 8. Two-Phase Motor Driver (L293D)

System Examples (continued)

9.3.2 DC Motor Controls

Figure 9 and Figure 10 below depict a typical setup for using the L293 device as a controller for DC motors. Note that the L293 device can be used as a simple driver for a motor to turn on and off in one direction, and can also be used to drive a motor in both directions. Refer to the function tables below to understand unidirectional vs bidirectional motor control. Refer to the *Recommended Operating Conditions* when considering the appropriate input high and input low voltage levels to enable each channel of the device.



Connections to ground and to supply voltage

Figure 9. DC Motor Controls

Table 2. Unidirectional DC Motor Control

EN	3A	M1 ⁽¹⁾	4A	M2
H	H	Fast motor stop	H	Run
H	L	run	L	Fast motor stop
L	X	Free-running motor stop	X	Free-running motor stop

(1) L = low, H = high, X = don't care

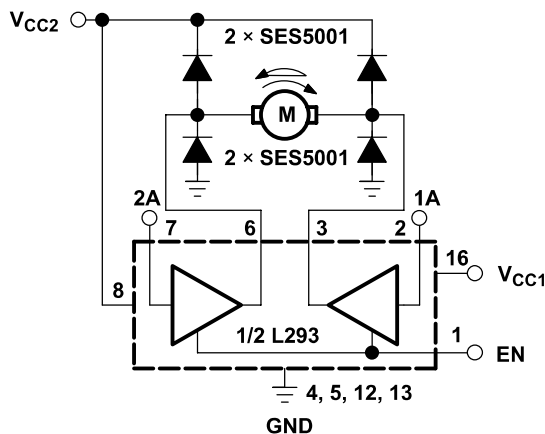


Figure 10. Bidirectional DC Motor Control

Table 3. Bidirectional DC Motor Control

EN	1A	2A	FUNCTION ⁽¹⁾
H	L	H	Turn right
H	H	L	Turn left

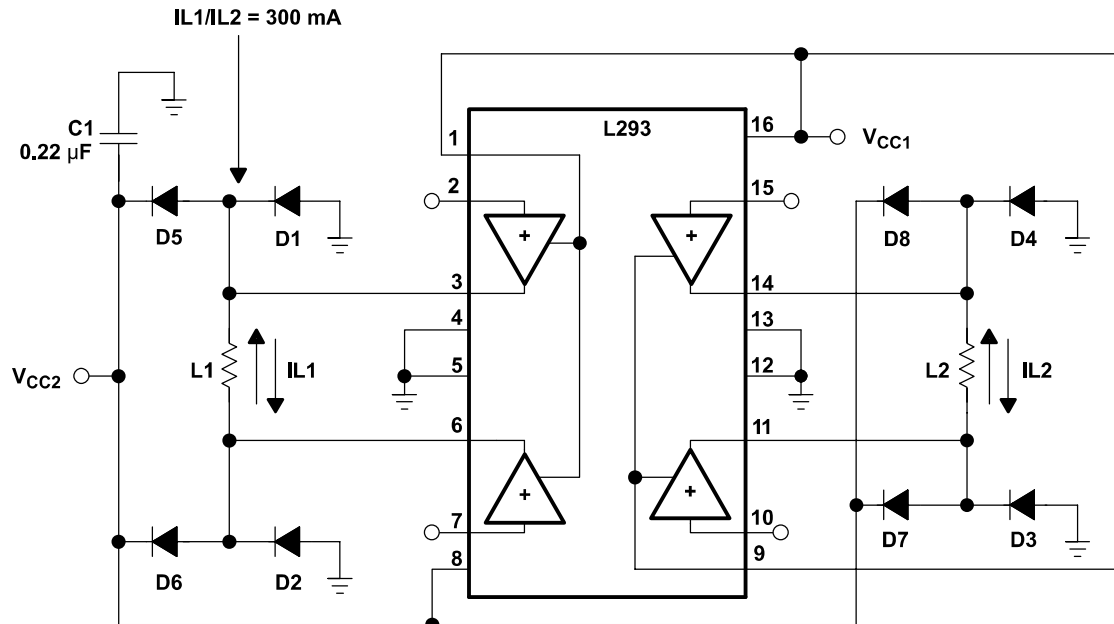
(1) L = low, H = high, X = don't care

Table 3. Bidirectional DC Motor Control (continued)

EN	1A	2A	FUNCTION ⁽¹⁾
H	L	L	Fast motor stop
H	H	H	Fast motor stop
L	X	X	Free-running motor stop

9.3.3 Bipolar Stepping-Motor Control

Figure 11 below depicts a typical setup for using the L293D as a two-phase motor driver. Refer to the [Recommended Operating Conditions](#) when considering the appropriate input high and input low voltage levels to enable each channel of the device.



D1–D8 = SES5001

Figure 11. Bipolar Stepping-Motor Control

10 Power Supply Recommendations

V_{CC1} is $5\text{ V} \pm 0.5\text{ V}$ and V_{CC2} can be same supply as V_{CC1} or a higher voltage supply with peak voltage up to 36 V. Bypass capacitors of 0.1 μF or greater should be used at V_{CC1} and V_{CC2} pins. There are no power up or power down supply sequence order requirements.

Properly heatsinking the L293 when driving high-current is critical to design. The $R_{thj-amp}$ of the L293 can be reduced by soldering the GND pins to a suitable copper area of the printed circuit board or to an external heat sink.

Figure 14 shows the maximum package power PT_{OT} and the θ_{JA} as a function of the side of two equal square copper areas having a thickness of 35 μm (see Figure 14). In addition, an external heat sink can be used (see Figure 12).

During soldering, the pin temperature must not exceed 260°C, and the soldering time must not exceed 12 seconds.

The external heatsink or printed circuit copper area must be connected to electrical ground.

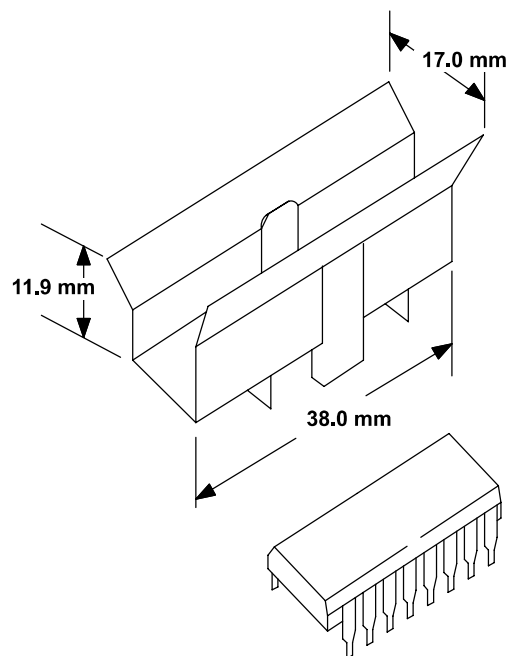


Figure 12. External Heat Sink Mounting Example ($\theta_{JA} = 25^\circ\text{C/W}$)

11 Layout

11.1 Layout Guidelines

Place the device near the load to keep output traces short to reduce EMI. Use solid vias to transfer heat from ground pins to ground plane of the printed-circuit-board.

11.2 Layout Example

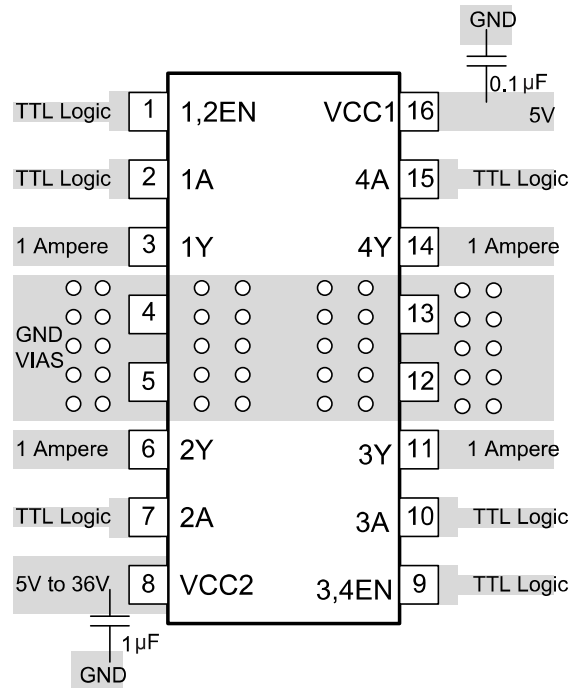


Figure 13. Layout Diagram

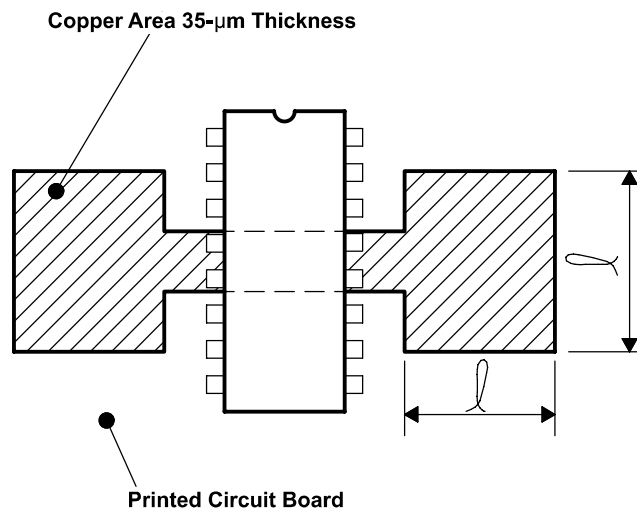


Figure 14. Example of Printed-Circuit-Board Copper Area (Used as Heat Sink)

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 4. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
L293	Click here	Click here	Click here	Click here	Click here
L293D	Click here	Click here	Click here	Click here	Click here

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.